PESD5V0F1BLD



Femtofarad bidirectional ESD protection diode

Rev. 1 — 23 July 2012

Product data sheet

Product profile

1.1 General description

Femtofarad bidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is encapsulated in a leadless ultra small DFN1006D-2 (SOD882D) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

The combination of extremely low capacitance, high ESD maximum rating and ultra small package makes the device ideal for high-speed data line protection and antenna protection applications.

1.2 Features and benefits

- Bidirectional ESD protection of one line ESD protection up to 10 kV
- Femtofarad capacitance: C_d = 400 fF
- Low ESD clamping voltage: 30 V at 30 ns and ±8 kV
- Very low leakage current: I_{RM} < 1 nA</p>
- IEC 61000-4-2; level 4 (ESD)
- Package height typ. 0.37 mm
- AEC-Q101 qualified

1.3 Applications

- 10/100/1000 Mbit/s Ethernet
- FireWire
- High-speed data lines
- SIM card protection
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals
- Audio and video equipment
- Antenna protection

1.4 Quick reference data

Table 1. Quick reference data

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per devi	ce					
V_{RWM}	reverse standoff voltage		-	-	5.5	V
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	-	0.4	0.55	pF



2. Pinning information

Table 2. Pinning

	•		
Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	1 2	1 2 sym045
		Transparent top view	

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PESD5V0F1BLD	DFN1006D-2	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882D			

4. Marking

Table 4. Marking codes

Type number	Marking code
PESD5V0F1BLD	Н

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
I _{PPM}	rated peak pulse current	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	2.5	Α
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		-40	+125	°C
T _{stg}	storage temperature		-55	+125	°C

^[1] Device stressed with ten non-repetitive current pulses (8/20 μ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

Table 6. ESD maximum ratings

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
Per device	ce				
V _{ESD} e	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1]</u> _	10	kV
		IEC 61000-4-2 (air discharge)	<u>[1]</u> -	10	kV
		MIL-STD-883 (human body model)	-	10	kV

^[1] Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
Per device	
IEC 61000-4-2; level 4 (ESD)	> 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV

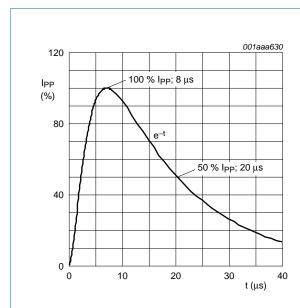


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

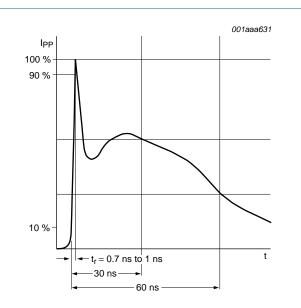


Fig 2. ESD pulse waveform according to IEC 61000-4-2

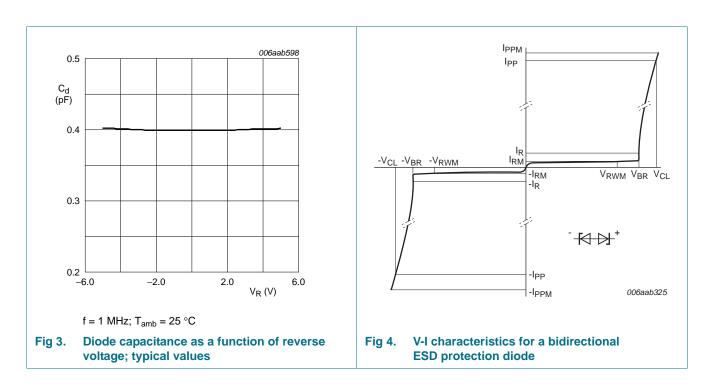
6. Characteristics

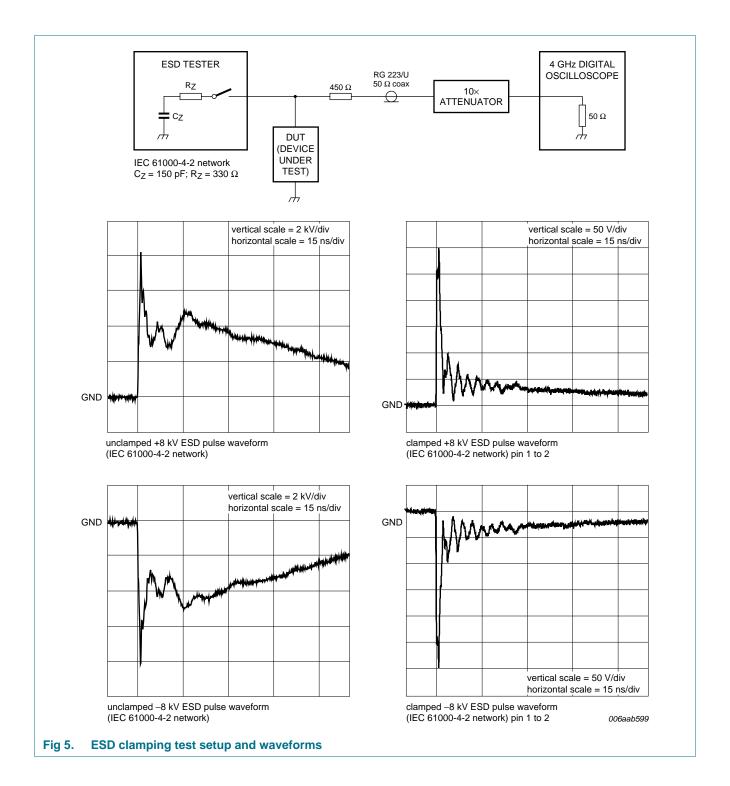
Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Cyllibol	Parameter	Conditions		Min	Тур	Max	Unit
Per devi	ce						
V_{RWM}	reverse standoff voltage			-	-	5.5	V
I _{RM}	reverse leakage current	$V_{RWM} = 5 V$		-	1	100	nA
V_{BR}	breakdown voltage	I _R = 1 mA		6	8	10	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$		-	0.4	0.55	pF
V_{CL}	clamping voltage	I _{PP} = 1 A	<u>[1]</u>	-	-	11	V
		I _{PPM} = 2.5 A	<u>[1]</u>	-	-	15	V
r _{dyn}	dynamic resistance	I _R = 10 A	[2]	-	1.5	-	Ω

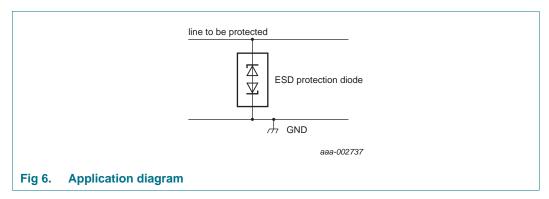
- [1] Device stressed with 8/20 µs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.
- [2] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5-1-2008.





7. Application information

The device is designed for the protection of one bidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both, positive and negative with respect to ground.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

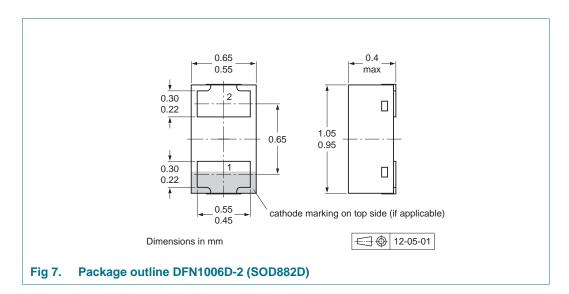
- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

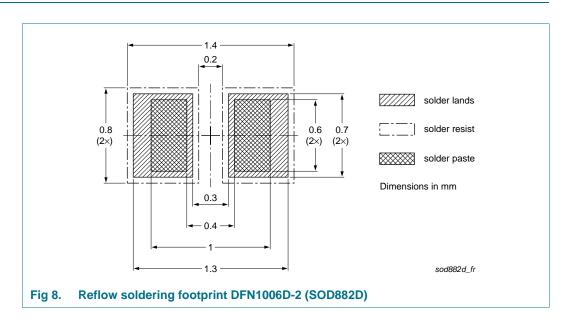
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	pe number Package Description		Packing quantity
			10000
PESD5V0F1BLD	DFN1006D-2 (SOD882D)	2 mm pitch, 8 mm tape and reel	-315

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



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12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0F1BLD v.1	20120723	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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